### **BCT4222B**

### **High-Speed DPDT Analog Switch**

#### **Features**

♦ V<sub>CC</sub> Operating Range: 1.65V to 4.5V

♦ Rail-to-Rail Signal Range

♦ ON-Resistance Matching: 0.05 Ω (TYP)

♦ ON-Resistance Flatness: 0.08Ω (TYP)

♦ High Off Isolation: 57dB at 10MHz

♦ 54dB (10MHz) Crosstalk Rejection Reduces Signal Distortion

◆ Break-Before-Make Switching

♦ -3dB Bandwidth: 350MHz

◆ Extended Industrial Temperature Range: –40°C to 85°C

◆ Improved Direct Replacement for NLAS7222

◆ Packaging (Pb-free & Green available)

#### **General Description**

The BCT4222B is a high bandwidth, fast double-pole double-throw (DPDT) analog switch. Its wide bandwidth and low bit-to-bit skew allow it to pass high-speed differential signals with good signal integrity. Each switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. Industry-leading advantages include a propagation delay of less than 250ps, resulting from its low channel resistance and low I/O capacitance. Its high channel-to-channel crosstalk rejection results in minimal noise interference.

#### **Applications**

Cell

Phones

**PDAs** 

Portable Instrumentation
Differential Signal Data Routings

USB 2.0 Signal Routing

#### **Connection Diagram**

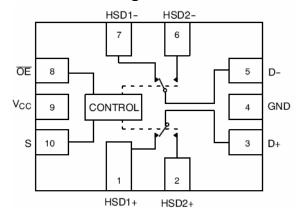


Figure 1. Pin Connections and Logic Diagram (BCT4222B Top View)



### **Pin Description**

Pin Number	Name	Description
10	S	Select Input
4	GND	Ground
1,2	HSD1+,HSD2+	Data Ports
7,6	HSD1-,HSD2-	Data Ports
3,5	D+, D-	Data Ports
9	VCC	Positive Power Supply
8	/OE	Output Enable

### **Logic Function Table**

/OE	S HSD1+,HSD1-		HSD2+,HSD2-
1	×	OFF	OFF
0	0	ON	OFF
0	1	OFF	ON

### **ORDERING INFORMATION**

Ordering Code	Package Description	Temp Range	Top Marking
BCT4222BETB-TR	10-pin WQFN 1.4X1.8	–40°C to +85°C	AJX



#### **MAXIMUM RATINGS**

Symbol	Pins	Parameter	Value	Unit	
V <sub>CC</sub>	V <sub>CC</sub>	Positive DC Supply Voltage	-0.5 to +4.6	V	
	HSD1+, HSD1-,				
	HSD1-,		-0.5 to V <sub>CC</sub> +0.3		
V <sub>IS</sub>	HSD2+,	Analog Signal Voltage	-0.5 to V <sub>CC</sub> +0.3	V	
	HSD2-				
	D+, D-		-0.5 to +4.6		
V <sub>IN</sub>	/OE, S	Control Input Voltage	-0.5 to +4.6	V	
Icc	V <sub>CC</sub>	Positive DC Supply Current	50	mA	
Ts		Storage Temperature	-65 to +150	°C	
I <sub>IN</sub>	/OE, S	Control Input Current	±20mA	mA	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

#### **ESD PROTECTION**

Symbol	Parameter	Value	Unit
ESD	Human Body Model - All Pins	2.0	kV
ESD	Human Body Model - I/O to GND	8.0	kV



#### RECOMMENDED OPERATING CONDITIONS

Symbol	Pins	Parameter	Min	Max	Unit
V <sub>CC</sub>		Positive DC Supply Voltage	1.65	4.5	V
	HSD1+,				
	HSD1-,		GND	Vcc	V
V <sub>IS</sub>	HSD2+,	Analog Signal Voltage			
	HSD2-				
	D+, D-		GND	4.5	
V <sub>IN</sub>	/OE, S	Digital Select Input Voltage	GND	V <sub>cc</sub>	V
T <sub>A</sub>		Operating Temperature Range	-40	+85	°C

Minimum and maximum values are guaranteed through test or design across the Recommended Operating Conditions, where applicable. Typical values are listed for guidance only and are based on the particular conditions listed for section, where applicable. These conditions are valid for all values found in the characteristics tables unless otherwise specified in the test conditions.



### **DC ELECTRICAL CHARACTERISTICS** (Typical: T = 25°C)

#### **BCT4222B SUPPLY AND LEAKAGE CURRENT**

			Test Conditions	V 00	-4	0°C to +85°	,C	Unit
Symbol	Pins	Parameter Test Condition	lest Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Unit
1	\/	Quiescent	$V_{IS} = V_{CC}$ or GND;	1.65 -4.5			1.0	uA
I <sub>CC</sub>	Vcc	Supply Current	$I_{OUT} = 0 A$		-	1	1.0	uA
		Increase in I <sub>CC</sub>						
Ісст	Vcc	per Control	$V_{IN} = 2.6 \text{ V}$	3.6	-	-	10	uA
		Voltage						
	HSD1+,	OFF State						
I <sub>OZ</sub>	HSD1-, HSD2+,	Leakage	$0 \le V_{IS} \le V_{CC}$	1.65 - 4.5	-	-	±1.0	uA
	HSD2-	Current						
	D+, D-	Power OFF						
I <sub>OFF</sub>		Leakage	0 ≤ V <sub>IS</sub> ≤4.5 V	0	-	-	±1.0	uA
		Current						

#### **BCT4222B DIGITAL INPUT VOLTAGE**

Symbol	Pins	Parameter	Test Conditions	V <sub>cc</sub> (V)	-4	Unit		
Symbol	FIIIS		rest Conditions	VCC (V)	Min	Тур	Max	Onit
V	S,/OE	Input High		3.6	1.6			V
V <sub>IH</sub>	5,/UE	Voltage			1.0	-		V
	S,/OE	Input Low						.,
V <sub>IL</sub>		Voltage		3.6	-	-	0.5	V
I <sub>IN</sub>	S,/OE	Input current	S, /OE = 0V or VCC		-	-	±1.0	uA



#### **BCT4222B HIGH SPEED ON RESISTANCE**

Cumbal	Dino	Parameter Tes	Toot Conditions	V 00	-40°C to +85°C			Unit
Symbol	Pins	Parameter	Test Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Unit
			V = 0.V to 0.4.V	2.7		9.0	12	
R <sub>ON</sub>		On-Resistance	$V_{IS} = 0 \text{ V to } 0.4 \text{ V},$	3.3		8.0	10	Ω
			$I_{ON} = 8 \text{ mA}$	4.5		7.0	8.0	
	On Basistana	On Registeres	V 0.V/to 0.4.V	2.7		1.6		
R <sub>FLAT</sub>		On-Resistance	$V_{IS} = 0 \text{ V to } 0.4 \text{ V},$	3.3		1.5		Ω
		Flatness	$I_{ON} = 8 \text{ mA}$	4.5		1.4		
		On-Resistance	$V_{IS} = 0 \text{ V to } 0.4 \text{ V},$	2.7		1.6		
R <sub>ON</sub>				3.3		1.5		Ω
		Matching	I <sub>ON</sub> =8 mA	4.5		1.4		

#### **BCT4222B DC ELECTRICAL CHARACTERISTICS**

(continued) FULL SPEED ON RESISTANCE (Typical: T = 25°C,  $V_{CC} = 3.3 \text{ V}$ )

Symbol	Dina	Doromotor	Toot Conditions	V 00	-40°C to +85°C			Unit
Symbol	Pins	Parameter	Test Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Unit
			V 0.V/to.V/	2.7		9.0	12	
R <sub>ON</sub>		On-Resistance	$V_{IS} = 0 \text{ V to } V_{CC},$	3.3		8.5	10.5	Ω
			I <sub>ON</sub> = 8 mA	4.5		7.5	8.5	
		On-Resistance $V_{IS} = 0 \text{ V to } V_{CC}$ Flatness $I_{ON} = 8 \text{ mA}$	V 0.V/to.V/	2.7		1.6		
R <sub>FLAT</sub>				3.3		1.5		Ω
			ION = O IIIA	4.5		1.4		
R <sub>ON</sub>		On-Resistance	$V_{IS} = 0 \text{ V to } V_{CC},$	2.7		2.20		
		Matching	$I_{ON} = 8 \text{ mA}$	3.3		2.45		Ω
		iviatoring	ION = O IIIA	4.5		2.65		



#### **BCT4222B AC ELECTRICAL CHARACTERISTICS**

TIMING/FREQUENCY (Typical: T = 25°C,  $V_{CC}$  = 3.3 V,  $R_L$  = 50 $\Omega$  ,  $C_L$  = 5 pF, f = 1 MHz)

Symbol	Pins	Darameter	eter Test Conditions	V 00	-40	)°C to +85°	°C	Unit
Symbol	Pilis	Parameter Test Condition		V <sub>CC</sub> (V)	Min	Тур	Max	Onit
t <sub>ON</sub>	Closed to	Turn ON Time	Soo toot circuit 2	1.65 - 4.5		4.4	20	20
	Open	Turn-ON Time	See test circuit 2	1.00 4.0		14	30	ns
	Open to	Turn-OFF Time	Contact simplify	1.65 - 4.5		10	20	20
t <sub>OFF</sub>	Closed	Tum-OFF Time	See test circuit 2	1.05 - 4.5		10	20	ns
<b>t</b>		Break-Before-Make	See test circuit 1	1.65 - 4.5	3.0	4.4	7.0	ns
t <sub>BBM</sub>		Delay	See lest circuit 1	1.03 - 4.3	5.0	4.4	7.0	115
BW		0 10 0 1 : 11	C <sub>L</sub> = 5 pF	1.65 - 4.5		300		MHz
DVV		-3 dB Bandwidth	C <sub>L</sub> = 0 pF	1.00 - 4.5		350		IVIITZ

#### **BCT4222B ISOLATION**

(Typical: T = 25°C,  $V_{CC}$  = 3.3 V,  $R_L$  =  $50\Omega$  ,  $C_L$  = 5 pF, f = 1 MHz)

Symbol	Pins	Parameter	Test Conditions	V <sub>cc</sub> (V)	-40°C to +85°C			Unit
	Pins				Min	Тур	Max	
OIDD	OIRR Open OFF-Isolation f = 250 MHz	1.65 -		-22		10		
OIRR	Open	Open OFF-Isolation	I = 250 MHZ	4.5		-22		dB
VTALK	HSD1+	Non-Adjacent		1.65 -		20		7
XTALK	to HSD1- Channel Crosstalk	f = 250 MHz	4.5		-30		dB	



#### **BCT4222B CAPACITANCE**

(Typical: T = 25°C,  $V_{CC} = 3.3$  V,  $R_L = 50\Omega$ ,  $C_L = 5$  pF, f = 1 MHz)

Symbol	Pins	Parameter	Test Conditions	-40°C to +85°C			11!6
				Min	Тур	Max	Unit
C <sub>IN</sub>	OE	Control Pin Input	V 0 V	-	3.0	-	pF
		Capacitance	$V_{CC} = 0 V$				
C <sub>ON</sub>	D+ to	ON Capacitance	V <sub>CC</sub> = 3.3 V; OE = 0 V	-	8.0	-	pF
	HSD1+ or						
	HSD2+						
Coff	HSD2+,	OFF Capacitance	V <sub>CC</sub> = V <sub>IS</sub> = 3.3 V; OE		4.5	-	pF
	HSD2-		= 3.3 V	-			

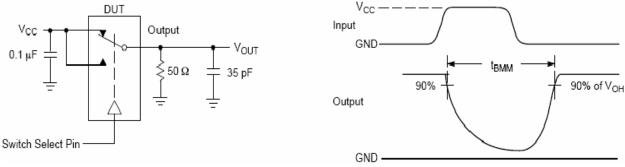


Figure 1. t<sub>BBM</sub> (Time Break-Before-Make)

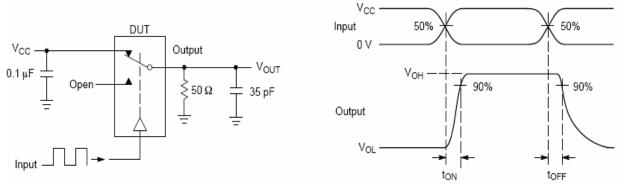


Figure 2. t<sub>ON</sub> / t<sub>OFF</sub>



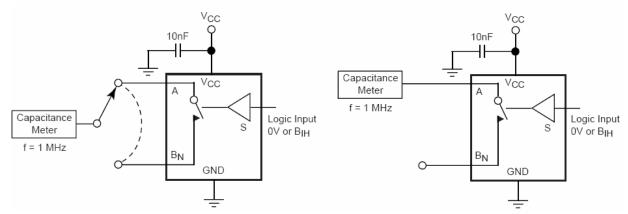


Figure 3. Channel ON/OFF Capacitance

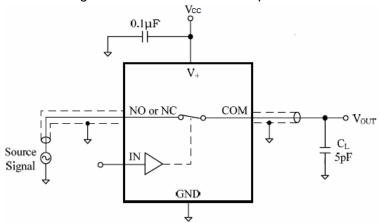


Figure 4. Bandwidth -3dB

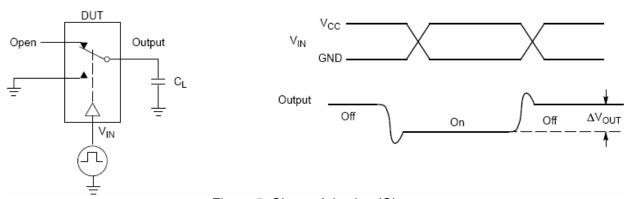


Figure 5. Charge Injecting (Q)



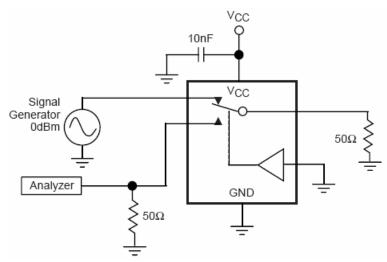


Figure 6. Crosstalk

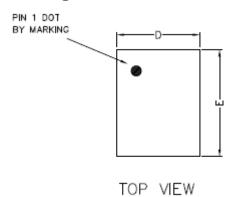
### **Applications Information**

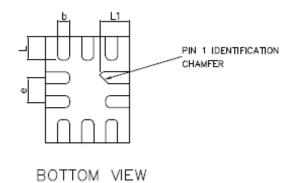
#### **Logic Inputs**

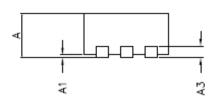
The logic control inputs can be driven up to +3.6V regardless of the supply voltage. For example, given a +3.3V supply, the output enables or select pins may be driven low to 0V and high to 3.6V.



### **Package Information**







COLUMNIA DINENCIONO(1111)									
COMMON DIMENSIONS(MM)									
PKG.	UT: ULTRA THIN								
REF.	MIN.	NOM.	MAX						
Α	0.50	0.55	0.60						
A1	0.00	_	0.05						
A3	0.15 REF.								
D	1.35	1.40	1.45						
E	1.75	1.80	1.85						
Ь	0.15	0.20	0.25						
L	0.30	0.40	0.50						
L1	0.40	0.50	0.60						
е	0.40 BSC								

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PI5A392AQEX PI5A392AQE FSA634UCX NX3L1T5157GMZ ADG714BCPZ-REEL7 HT4051ARZ TC4066BP(N,F) DG302BDJ-E3

ADG854BCPZ-REEL7 PI5A100WE PI5A100QEX HV2733FG-G HV2701FG-G HV2301FG-G HV2301FG-G-M931 RS2117YUTQK10

RS2118YUTQK10 RS2227XUTQK10 ADG452BRZ-REEL7 MAX391CPE+ MAX4744ELB+ MAX4730EXT+T MAX4730ELT+

MAX333AEWP+ BU4066BC MAX313CPE+ BU4S66G2-TR NLASB3157MTR2G NX3L4684TK,115 NX5L2750CGUX

NLAS4157DFT2G NLAS4599DFT2G NLASB3157DFT2G NLAST4599DFT2G NLAST4599DTT1G